74AUP1T57

Low-power configurable gate with voltage-level translator

Rev. 6 — 26 May 2021 Product data sheet

1. General description

The 74AUP1T57 is a configurable multiple function gate with level translating, Schmitt-trigger inputs. The device can be configured as any of the following logic functions AND, OR, NAND, NOR, XNOR, inverter and buffer; using the 3-bit input. All inputs can be connected directly to V_{CC} or GND. Low threshold Schmitt trigger inputs allow these devices to be driven by 1.8 V logic levels in 3.3 V applications.

This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 2.3 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 2.3 V to 3.6 V
- · High noise immunity
- Low static power consumption; I_{CC} = 1.5 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74AUP1T57GW	-40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363					
74AUP1T57GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886					
74AUP1T57GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115					
74AUP1T57GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202					



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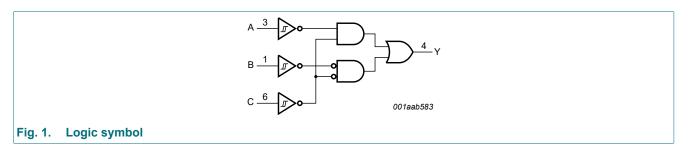
4. Marking

Table 2. Marking

Type number	Marking code [1]
74AUP1T57GW	a7
74AUP1T57GM	a7
74AUP1T57GN	a7
74AUP1T57GS	a7

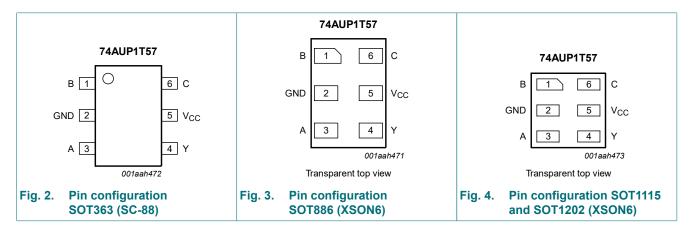
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



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6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
В	1	data input
GND	2	ground (0 V)
A	3	data input
Υ	4	data output
V _{CC}	5	supply voltage
С	6	data input

7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Input			Output
С	В	A	Υ
L	L	L	Н
L	L	Н	L
L	Н	L	Н
L	Н	Н	L
Н	L	L	L
Н	L	Н	L
Н	Н	L	Н
Н	Н	Н	Н

7.1. Logic configurations

Table 5. Function selection table

Logic function	Figure
2-input AND	see Fig. 5
2-input AND with both inputs inverted	see Fig. 8
2-input NAND with inverted input	see Fig. 6 and Fig. 7
2-input OR with inverted input	see Fig. 6 and Fig. 7
2-input NOR	see Fig. 8
2-input NOR with both inputs inverted	see Fig. 5
2-input XNOR	see Fig. 9
Inverter	see Fig. 10
Buffer	see Fig. 11

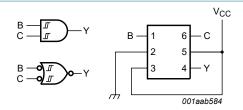


Fig. 5. 2-input AND gate or 2-input NOR gate with both inputs inverted

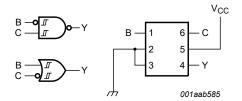


Fig. 6. 2-input NAND gate with input B inverted or 2-input OR gate with inverted C input

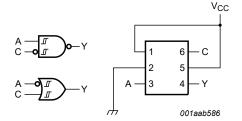


Fig. 7. 2-input NAND gate with input C inverted or 2-input OR gate with inverted A input

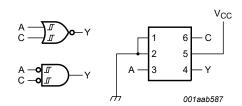


Fig. 8. 2-input NOR gate or 2-input AND gate with both inputs inverted

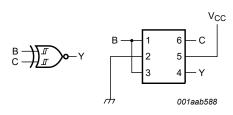


Fig. 9. 2-input XNOR gate

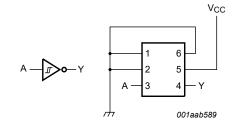


Fig. 10. Inverter

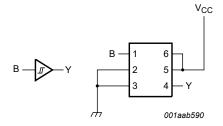


Fig. 11. Buffer

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8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
I _O	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I_{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		2.3	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

^[2] For SOT363 (SC-88) package: Ptot derates linearly with 3.7 mW/K above 83 °C.

For SOT886 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

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10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{T+}	positive-going threshold	V _{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	V _{CC} = 3.0 V to 3.6 V	0.75	-	1.16	V
V _{T-}	negative-going threshold	V _{CC} = 2.3 V to 2.7 V	0.35	-	0.60	V
	voltage	V _{CC} = 3.0 V to 3.6 V	0.50	-	0.85	V
V _H	hysteresis voltage	$(V_H = V_{T+} - V_{T-})$				
		V _{CC} = 2.3 V to 2.7 V	0.23	-	0.60	V
		V _{CC} = 3.0 V to 3.6 V	0.25	-	0.56	V
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 2.3 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 2.3 V to 3.6 V	-	-	0.10	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.1	μA
Δl _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 2.3 V to 3.6 V	-	-	1.2	μΑ
ΔI _{CC}	additional supply current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V; } I_{O} = 0 \text{ A}$	-	-	-	μA
		V _{CC} = 3.0 V to 3.6 V; I _O = 0 A	[2] -	-	-	μΑ
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND or V_{CC}	-	0.8	-	pF
Co	output capacitance	V _O = GND; V _{CC} = 0 V	-	1.7	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +85 °C					
V _{T+}	positive-going threshold	V _{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	V _{CC} = 3.0 V to 3.6 V	0.75	-	1.19	V
V _{T-}	negative-going threshold	V _{CC} = 2.3 V to 2.7 V	0.35	-	0.60	V
	voltage	V _{CC} = 3.0 V to 3.6 V	0.50	-	0.85	V
V _H	hysteresis voltage	$(V_H = V_{T+} - V_{T-})$				
		V _{CC} = 2.3 V to 2.7 V	0.10	-	0.60	V
		V _{CC} = 3.0 V to 3.6 V	0.15	-	0.56	V
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = -20 μ A; V_{CC} = 2.3 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	1.97	-	-	V
		I_{O} = -3.1 mA; V_{CC} = 2.3 V	1.85	-	-	V
		I_{O} = -2.7 mA; V_{CC} = 3.0 V	2.67	-	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
	$I_{O} = 20 \mu A$; $V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$		-	-	0.1	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μΑ
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μΑ
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.5	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 2.3 V to 3.6 V	-	-	1.5	μA
ΔI _{CC}	additional supply current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V; } I_{O} = 0 \text{ A}$ [1]	-	-	4	μΑ
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } I_O = 0 \text{ A}$ [2]	-	-	12	μA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +125 °C					
V _{T+}	positive-going threshold	V _{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	V _{CC} = 3.0 V to 3.6 V	0.75	-	1.19	V
V _{T-}	negative-going threshold	V _{CC} = 2.3 V to 2.7 V	0.33	-	0.64	V
	voltage	V _{CC} = 3.0 V to 3.6 V	0.46	-	0.85	V
V _H	hysteresis voltage	$(V_{H} = V_{T+} - V_{T-})$				
		V _{CC} = 2.3 V to 2.7 V	0.10	-	0.60	V
		V _{CC} = 3.0 V to 3.6 V	0.15	-	0.56	V
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = -20 μ A; V_{CC} = 2.3 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 2.3 V to 3.6 V	-	-	0.11	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V to } 3.6 \text{ V; } V_{CC} = 0 \text{ V}$	-	-	±0.75	μA
Δl _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.75	μΑ
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 2.3 V to 3.6 V	-	-	3.5	μΑ
ΔI _{CC}	additional supply current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V; } I_{O} = 0 \text{ A}$ [1]	-	-	7	μΑ
		V _{CC} = 3.0 V to 3.6 V; I _O = 0 A [2]	-	-	22	μA

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 13.

Symbol	Parameter	Conditions	25 °C		25 °C -40 °C to -40 °C to +85 °C +125 °C					Unit
				Typ[1]	Max	Min	Max	Min	Max	
V _{CC} = 2.3 V to 2.7 V; V _I = 1.65 V to 1.95 V										
t _{pd}	propagation	A, B, C to Y; see <u>Fig. 12</u> [2]								
	delay	C _L = 5 pF	2.1	3.6	5.5	0.5	6.8	0.5	7.5	ns
		C _L = 10 pF	2.6	4.1	6.2	1.0	7.9	1.0	8.7	ns
		C _L = 15 pF	2.9	4.6	6.8	1.0	8.7	1.0	9.6	ns
		C _L = 30 pF	3.8	5.8	8.2	1.5	10.8	1.5	11.9	ns

One input at 0.3 V or 1.1 V, other input at V_{CC} or GND. One input at 0.45 V or 1.2 V, other input at V_{CC} or GND.

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Symbol	Parameter	Parameter Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
V _{CC} = 2.	3 V to 2.7 V; V _I =	= 2.3 V to 2.7 V								
t _{pd}	propagation	A, B, C to Y; see Fig. 12 [2]								
	delay	C _L = 5 pF	1.7	3.4	5.4	0.5	6.0	0.5	6.6	ns
		C _L = 10 pF	2.1	4.0	6.2	1.0	7.1	1.0	7.9	ns
		C _L = 15 pF	2.5	4.5	6.7	1.0	7.9	1.0	8.7	ns
		C _L = 30 pF	3.3	5.6	8.2	1.5	10.0	1.5	11.0	ns
V _{CC} = 2.	3 V to 2.7 V; V _I =	= 3.0 V to 3.6 V	'			'	'	'	'	
t _{pd}	propagation	A, B, C to Y; see <u>Fig. 12</u> [2]								
	delay	C _L = 5 pF	1.4	3.2	4.9	0.5	5.5	0.5	6.1	ns
		C _L = 10 pF	1.8	3.7	5.7	1.0	6.5	1.0	7.2	ns
		C _L = 15 pF	2.2	4.2	6.3	1.0	7.4	1.0	8.2	ns
		C _L = 30 pF	3.0	5.4	7.8	1.5	9.5	1.5	10.5	ns
$V_{CC} = 3$.	0 V to 3.6 V; V _I =	= 1.65 V to 1.95 V						ı		
t _{pd}	propagation delay	A, B, C to Y; see <u>Fig. 12</u> [2]								
		C _L = 5 pF	2.0	2.9	3.9	0.5	8.0	0.5	8.8	ns
		C _L = 10 pF	2.5	3.5	4.6	1.0	8.5	1.0	9.4	ns
		C _L = 15 pF	2.8	3.9	5.2	1.0	9.1	1.0	10.1	ns
		C _L = 30 pF	3.6	5.1	6.6	1.5	9.8	1.5	10.8	ns
$V_{CC} = 3$.	0 V to 3.6 V; V _I =	= 2.3 V to 2.7 V								
t _{pd}	propagation	A, B, C to Y; see Fig. 12 [2]								
·	delay	C _L = 5 pF	1.6	2.8	4.2	0.5	5.3	0.5	5.9	ns
		C _L = 10 pF	2.0	3.4	4.9	1.0	6.1	1.0	6.8	ns
		C _L = 15 pF	2.3	3.9	5.5	1.0	6.8	1.0	7.5	ns
		C _L = 30 pF	3.1	5.0	6.9	1.5	8.5	1.5	9.4	ns
$V_{CC} = 3$.	0 V to 3.6 V; V _I =	= 3.0 V to 3.6 V						ı		
t _{pd}	propagation	A, B, C to Y; see Fig. 12 [2]								
·	delay	C _L = 5 pF	1.3	2.8	4.2	0.5	4.7	0.5	5.2	ns
		C _L = 10 pF	1.7	3.3	4.9	1.0	5.7	1.0	6.3	ns
		C _L = 15 pF	2.0	3.8	5.5	1.0	6.2	1.0	6.9	ns
		C _L = 30 pF	2.8	4.9	7.0	1.5	7.8	1.5	8.6	ns
T _{amb} = 2	5 °C	1				1		1		
C _{PD}	power	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3]								
	dissipation	V _{CC} = 2.3 V to 2.7 V	-	3.6	-	-	-	-	-	pF
	capacitance	V _{CC} = 3.0 V to 3.6 V	_	4.3	-	_	-	-	_	pF

^[1] All typical values are measured at nominal V_{CC}.

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

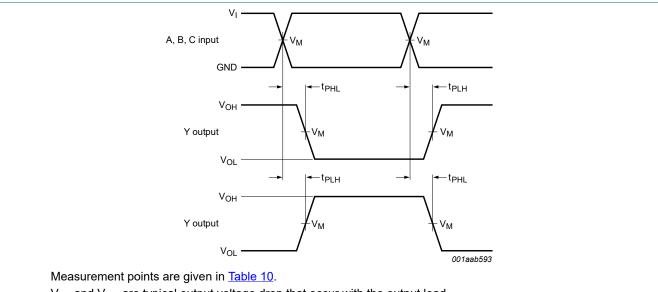
N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

 ^[2] t_{pd} is the same as t_{PLH} and t_{PHL}
 [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 P_D = C_{PD} × V_{CC}² × f_i × N + Σ(C_L × V_{CC}² × f_o) where:

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11.1. Waveforms and test circuit

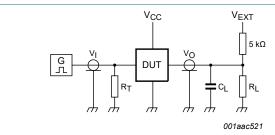


 $\ensuremath{V_{\text{OL}}}$ and $\ensuremath{V_{\text{OH}}}$ are typical output voltage drop that occur with the output load.

Fig. 12. Input A, B and C to output Y propagation delay times

Table 10. Measurement points

Supply voltage	Output	Input		
V _{CC}	V _M	V _M	VI	$t_r = t_f$
2.3 V to 3.6 V	0.5 × V _{CC}	0.5 × V _I	1.65 V to 3.6 V	≤ 3.0 ns



Test data is given in Table 11.

Definitions for test circuit:

 R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig. 13. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load		je Load V _{EXT}		
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
2.3 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times R_L = 5 $k\Omega.$

For measuring propagation delays, setup and hold times and pulse width R_L = 1 $M\Omega$.

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12. Package outline

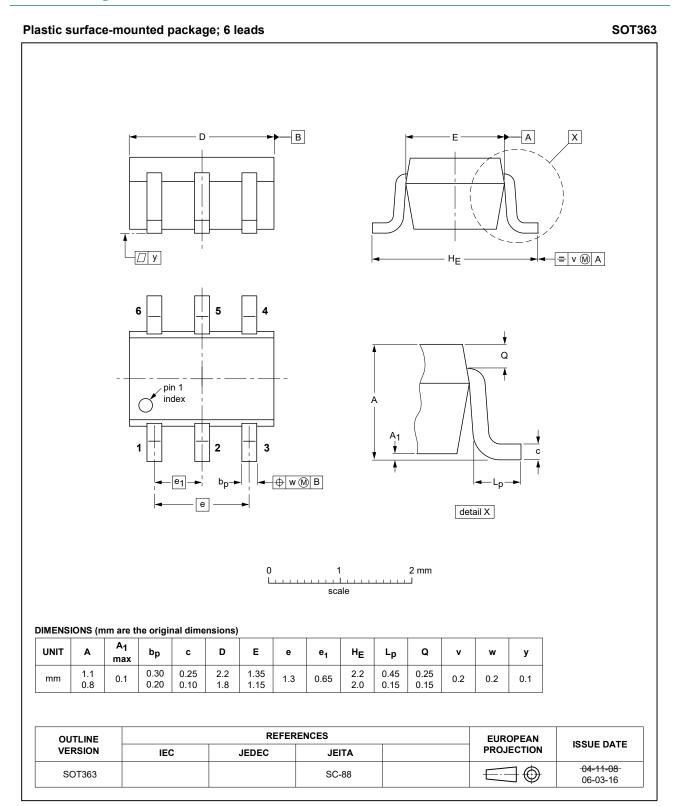


Fig. 14. Package outline SOT363 (SC-88)

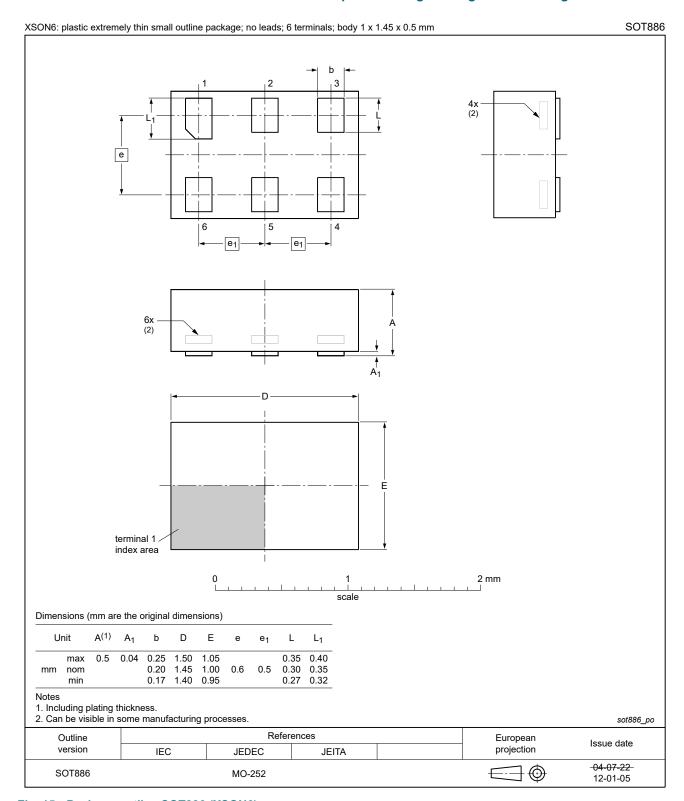


Fig. 15. Package outline SOT886 (XSON6)

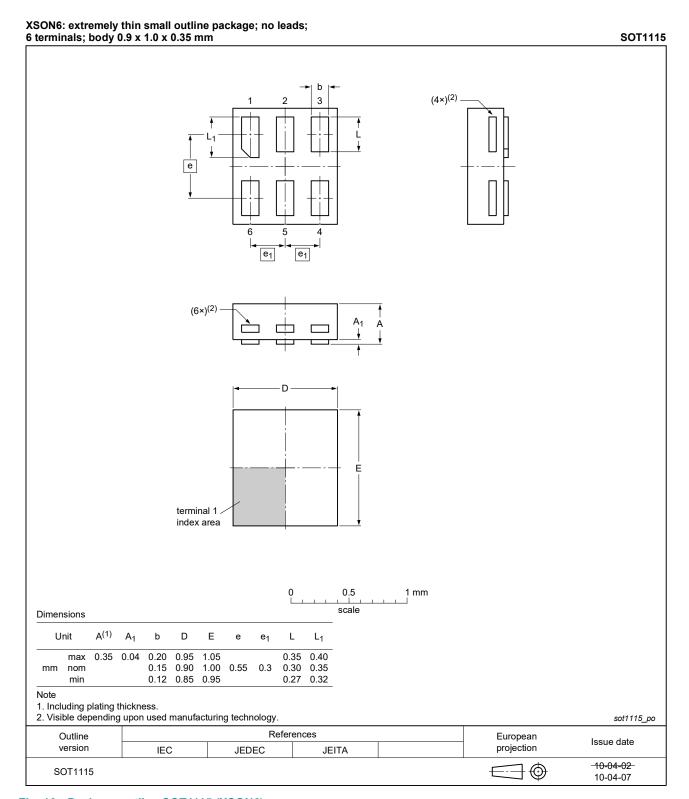


Fig. 16. Package outline SOT1115 (XSON6)

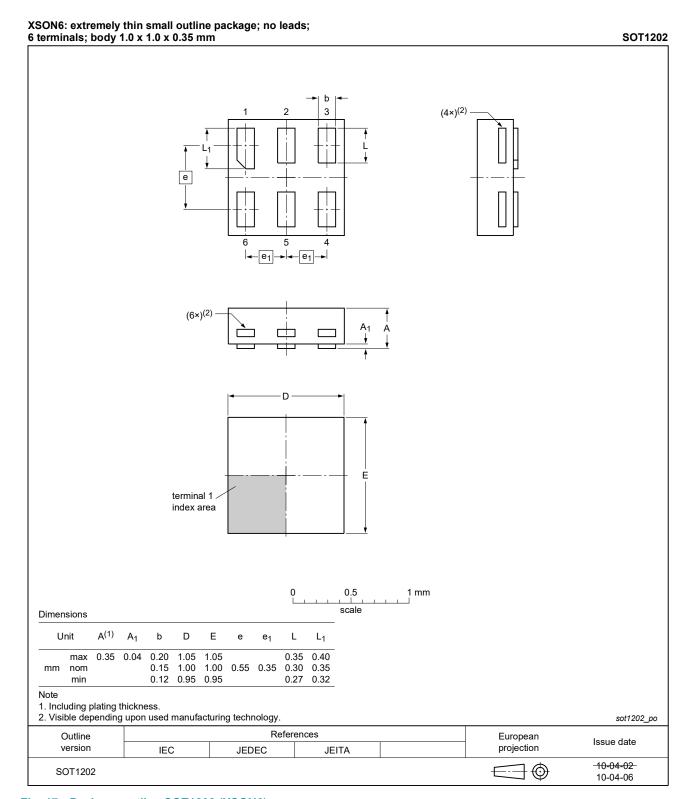


Fig. 17. Package outline SOT1202 (XSON6)

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13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AUP1T57 v.6	20210526	Product data sheet	-	74AUP1T57 v.5	
Modifications:	guidelines Legal texts Type numb Section 1	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type number 74AUP1T57GF (SOT891 / XSON6) removed. Section 1 and Section 2 updated. Section 8: Derating values for Ptot total power dissipation updated. 			
74AUP1T57 v.5	20120815	Product data sheet	-	74AUP1T57 v.4	
Modifications:	Package or	Package outline drawing of SOT886 (Fig. 15) modified.			
74AUP1T57 v.4	20111201	Product data sheet	-	74AUP1T57 v.3	
74AUP1T57 v.3	20100721	Product data sheet	-	74AUP1T57 v.2	
74AUP1T57 v.2	20090803	Product data sheet	-	74AUP1T57 v.1	
74AUP1T57 v.1	20080103	Product data sheet	-	-	

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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